

Thyristor Module

V_{RRM} / **V**_{DRM} 800 to 1600V

 Itav
 110 Amp

 Itrms
 170 Amp

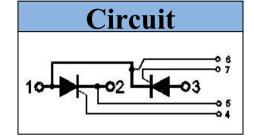
Features

- Aluminum oxide DBC
- Glass passivated chip
- Thyristor for line frequency
- Long-term stability

Applications

- Power converters
- Lighting control
- DC motor control and drives
- Heat and temperature control





Module Type

Туре	V _{RRM} / V _{DRM}	V _{RSM}
MTC110G-08	800V	900V
MTC110G-12	1200V	1300V
MTC110G-16	1600V	1700V

Maximum Ratings

Symbol	Item	Conditions	Values	Unit
I _{TAV}	Average On-state Current	180° Conduction Sin Half Wave, T _c = 85°C	110	А
I _{TRMS}	RMS On-state Current		170	Α
I _{TSM}	Surge On-state Current	$T_j = 25$ °C, $t = 50$ Hz(10ms), $V_R = 0$ V	2850	Α
I ² t	Circuit Fusing Consideration	t = 10ms T _j =25°C	40600	A ² s
Viso	Isolation Breakdown Voltage	AC 50Hz/60Hz; R.M.S; 1min	3000	V
Tj	Operating Junction Temperature		-40 to + 125	°C
T _{stg}	Storage Temperature		-40 to + 125	°C
Mt	Mounting Torque	To Terminals(M5)	3±15%	
Ms	Mounting Torque	To Heatsink(M6)	5±15%	N⋅m
Weight	Module (Approximately)		105	g
di/dt	Critical Rate of Rise of On-state Current, Max	T_j = 125°C, V_D = 1/2 V_{DRM} , I_G = 150mA, di_G /dt = 0.1A/ μ s	150	A/μs

Thermal Characteristics

Symbol	Item	Conditions	Values	Unit
R _{th(j-c)}	Thermal Impedance, Max	Junction to Case(Per Thyristor)	0.22	°C/W
R _{th(c-s)}	Thermal Impedance, Max	Case to Heat Sink	0.1	°C/W



■ Electrical Characteristics

Symbol	Item	Conditions	Values			Unit
			Min.	Тур.	Max.	Julia
V _{TM}	Peak On-State Voltage, Max	$T_j = 25^{\circ}C, I_T = 330A$	-	-	1.65	V
I _{DRM}	Repetitive Peak Reverse Current, Max /Repetitive Peak Off-state Current, Max	$T_j = 125$ °C, $V_R = V_{RRM}$, $V_D = V_{DRM}$	-	-	20	mA
V _{GT}	Gate Trigger Voltage, Max	$T_j = 25^{\circ}C, V_D = 6V$	-	-	3.0	V
I _{GT}	Gate Trigger Current, Max	$T_j = 25^{\circ}C, V_D = 6V$	-	-	150	mA
V_{GD}	Gate Non-Trigger Voltage, Max	$T_j = 125$ °C, $V_D = 2/3V_{DRM}$	-	-	0.25	V
IL	Latching Current	T _j = 25°C	-	200	-	mA
I _H	Holding Current	T _j = 25°C	-	150	-	mA
t _{gt}	Turn On Time	T _j = 25°C	-	3	-	μs
dv/dt	Critical Rate of Rise of Off-state Voltage, Min	T _j = 125°C, V _D = 2/3V _{DRM} Linear Voltage Rise	1000		V/µs	
V _{T0}	Threshold Voltage, for power loss calculation only	T _j = 125°C	0.85		V	
r _T	Slope Resistance, for power loss calculation only	T _j = 125°C	2.4		mΩ	

Performance Curves

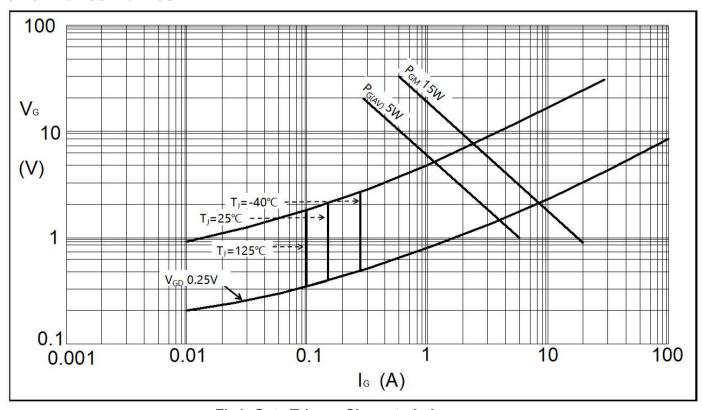


Fig1. Gate Trigger Characteristics



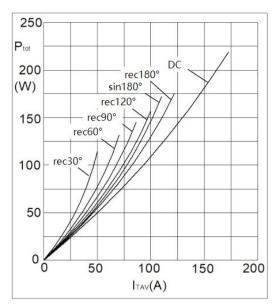


Fig2. Power Dissipation

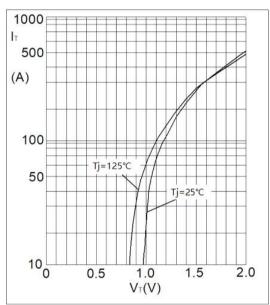


Fig4. Forward Characteristics

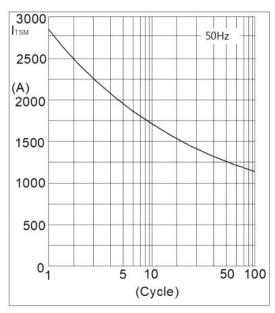


Fig6. Max Non-Repetitive Forward Surge Current

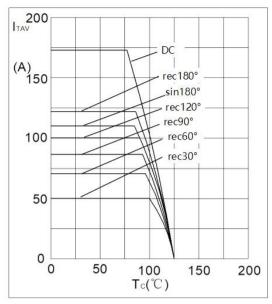


Fig3. Forward Current Derating Curve

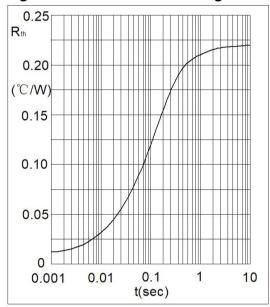
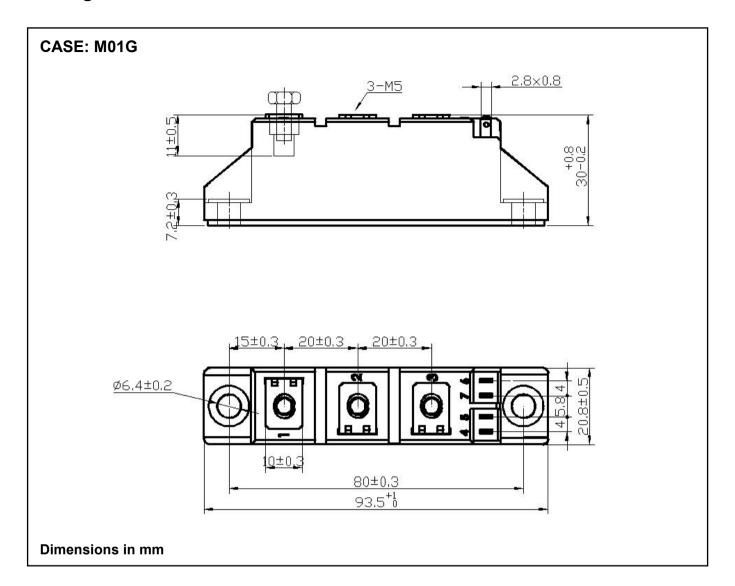


Fig5. Transient Thermal impedance



Package Outline Information



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